

Maximum Ratings (@ $T_A = +25$ °C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	Condition
Peak Pulse Current	lpp	1.5	Α	8/20µs (Note 7)
ESD Protection – Contact Discharge	V _{ESD_CONTACT}	±15	kV	Standard IEC61000-4-2
ESD Protection – Air Discharge	V _{ESD_AIR}	±15	kV	Standard IEC61000-4-2

Thermal Characteristics

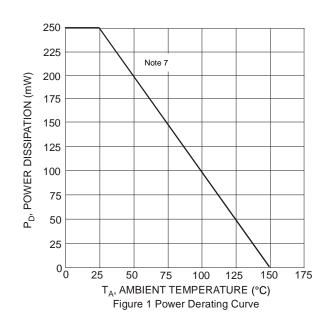
Characteristic	Symbol	Value	Unit
Power Dissipation (Note 7)	P_{D}	300	mW
Thermal Resistance, Junction to Ambient T _A = +25°C	$R_{ heta JA}$	417	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

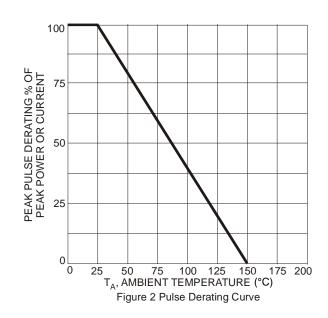
Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Reverse Standoff Voltage	V_{RWM}	_	_	5.5	V	-
Channel Leakage Current (Note 8)	I _R	-	_	100	nA	$V_R = 5V$, Any I/O to GND
Reverse Breakdown Voltage	V_{BR}	6.0	_	_	V	I _R = 1mA
Clamping Voltage, Positive Transients (Note 9)	V _C	_	10	12	V	$I_{PP} = 1A$, $t_P = 8/20 \mu s$
Channel Input Capacitance (Note 10)	C _T	_	0.5	_	pF	$V_R = 0V$, $f = 1MHz$, Any I/O to GND
		_	0.4	0.65		$V_R = 2.5V$, $f = 1MHz$, Any I/O to GND
Dynamic Resistance	R_{DYN}	_	0.9	_	Ω	$I_{PP} = 1A$, $t_P = 8/20 \mu s$

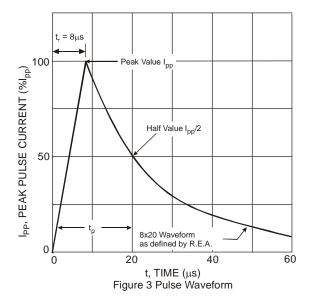
Notes:

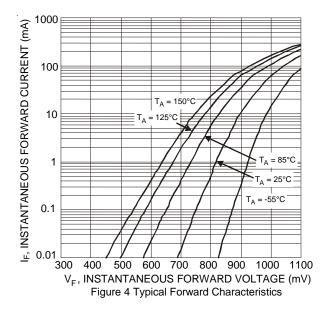
- 7. Device mounted on FR-4 PCB pad layout (2oz copper) as shown on Diodes Incorporated's suggested pad layout, which can be found on our website at http://www.diodes.com/package-outlines.html.
- 8. Short duration pulse test used to minimize self-heating effect.
- 9. Clamping voltage value is based on an 8x20µs peak pulse current (I_{PP}) waveform.
- 10. Measured from any I/O to GND.

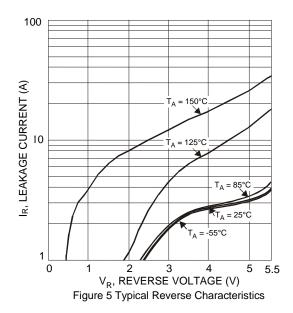












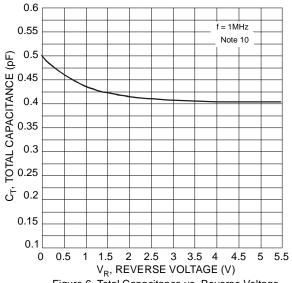


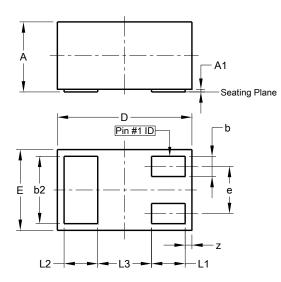
Figure 6 Total Capacitance vs. Reverse Voltage



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

X1-DFN1006-3

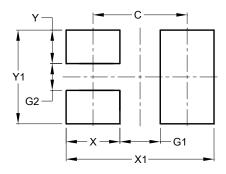


X1-DFN1006-3				
Dim	Min	Max	Тур	
Α	0.47	0.53	0.50	
A1	0.00	0.05	0.03	
b	0.10	0.20	0.15	
b2	0.45	0.55	0.50	
D	0.95	1.075	1.00	
Е	0.55	0.675	0.60	
е	-	-	0.35	
L1	0.20	0.30	0.25	
L2	0.20	0.30	0.25	
L3	-	-	0.40	
z	0.02	0.08	0.05	
All Dimensions in mm				

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

X1-DFN1006-3



Dimensions	Value (in mm)
С	0.70
G1	0.30
G2	0.20
Х	0.40
X1	1.10
Υ	0.25
Y1	0.70



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